DRV5015-Q1 車載用、低電圧、高感度のデジタル・ラッチ・ホール・エフェクト・センサ

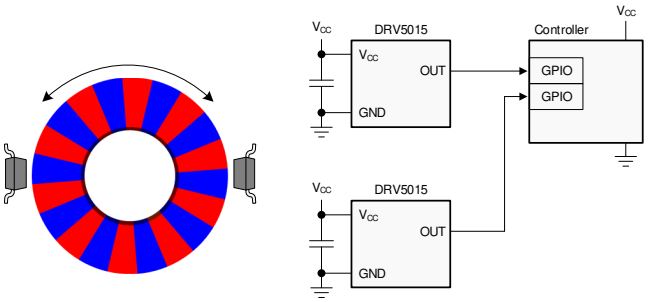
1 特長

- 車載アプリケーションに対応
- 下記内容で AEC-Q100 認定済み
  - デバイス温度グレード 0:動作時周囲温度範囲 –40°C～150°C
  - デバイス HBM ESD 分類レベル H3A
  - デバイス CDM ESD 分類レベル C6
- デジタル・ラッチ・ホール効果センサ
- 高精度の磁気感度
  - DRV5015A1-Q1:±0.7mT (標準値)
  - DRV5015A2-Q1:±1.8mT (標準値)
  - DRV5015A3-Q1:±1.8mT (反転、標準値)
- ヒステリシス内蔵
- 高速な 30kHz センシング帯域幅
- 2.5V～5.5V の V_{CC} 範囲で動作
- 20mA の電流を出力可能なオープン・ドレイン出力

2 アプリケーション

- ブラシレスDCモータ・センサ
  - 燃料ポンプ
  - 電動パワー・ステアリング
  - 電動サンルーフ
  - パワー・ウィンドウ
  - スライド式ドア
- インクリメンタル・ロータリー・エンコーダ
  - モータ速度 (タコメータ)
  - 機械的移動
  - 流量測定
  - ヒューマン・インターフェイスのノブ
  - 車輪の速度

代表的な回路図



3 概要

DRV5015-Q1は低電圧のデジタル・ラッチ・ホール・エフェクト・センサで、高速および高温のモータ・アプリケーション用に設計されています。このデバイスは2.5V～5.5Vの電源で動作し、磁束密度を検出して、事前定義された磁気スレッショルドに基づいてデジタルで出力します。

出力をトグルするにはN極とS極の切り替えが必要で、内蔵のヒステリシスにより堅牢なスイッチングが行われます。

このデバイスは2つの磁気スレッショルド・オプションおよび1つの反転出力オプションで供給されます。磁気感度が高いため、低コストの磁石を選択し、コンポーネントを柔軟に配置できます。

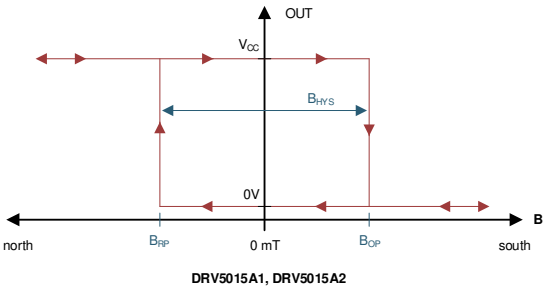
このデバイスは、-40°C～+150°Cの広い周囲温度範囲で一貫した動作を行います。

製品情報(1)

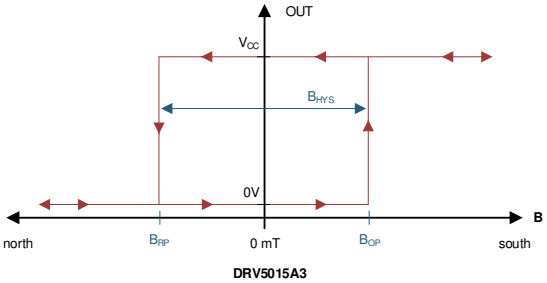
型番	パッケージ	本体サイズ(公称)
DRV5015-Q1	SOT-23 (3)	2.92mm×1.30mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にあるパッケージ・オプションについての付録を参照してください。

磁気応答



DRV5015A1, DRV5015A2



DRV5015A3

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4 改訂履歴

Revision A (November 2018) から **Revision B** に変更 **Page**

- Changed output voltage max value from V_{CC} + 0.3 V to 6.0 V in the *Absolute Maximum Ratings* table ... 3
- Changed T_A = –40℃ to +150℃ min and max values in *Magnetic Characteristics* table ... 4
- Added T_A = –40℃ to +125℃ limits to the *Magnetic Characteristics* table ... 4

2018年**9**月発行のものから更新 **Page**

- 変更 maximum temperature inside the motor from 125°C to 150°C in Table 1 ... 13

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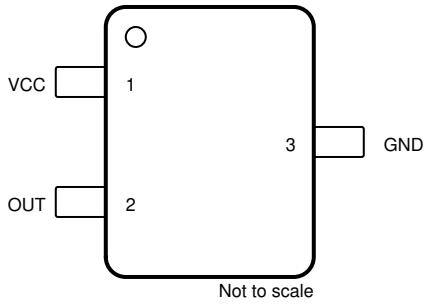
5 Pin Configuration and Functions

DBZ Package
3-Pin SOT-23
Top View



Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
GND	3	Ground	Ground reference.
OUT	2	Output	Open-drain output.
VCC	1	Power supply	2.5-V to 5.5-V power supply. Connect a ceramic capacitor with a value of at least 0.01 µF between VCC and ground.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V_{CC}	Power supply voltage	–0.3	6.0	V
V_{OUT}	Output voltage	–0.3	6.0	V
I_{OUT}	Output current		30	mA
B_{MAX}	Magnetic flux density		Unlimited	T
T_J	Operating junction temperature	–40	170	°C
T_{stg}	Storage temperature	–65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

over operating free-air temperature range (unless otherwise noted)

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002(1)	±5000	V
		Charged device model (CDM), per AEC Q100-011	±1500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

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6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{CC}	Power supply voltage	2.5	5.5	V
V_{OUT}	Output pin voltage	0	5.5	V
I_{OUT}	Output sinking current	0	20	mA
T_A	Operating ambient temperature	–40	150	°C

6.4 Thermal Information

THERMAL METRIC(1)		DRV5015-Q1 SOT-23 (DBZ) 3 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	356	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	128	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	94	°C/W
Y_{JT}	Junction-to-top characterization parameter	11.4	°C/W
Y_{JB}	Junction-to-board characterization parameter	92	°C/W

(1) For information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

at V_{CC} = 2.5 V to 5.5 V, over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITION	MIN	TYP	MAX	UNIT
I_{CC}	Operating supply current			2.3	2.8	mA
t_{ON}	Power-on time			40	70	µs
t_d	Propagation delay time(1)	B = B_{RP} – 10 mT to B_{OP} + 10 mT in 1 µs		13	25	µs
I_{OZ}	High-impedance output leakage current	5.5 V applied to OUT, while OUT is high-impedance			100	nA
V_{OL}	Low-level output voltage	I_{OUT} = 20 mA		0.15	0.4	V

(1) See the *Propagation Delay* section for more information.

6.6 Magnetic Characteristics

at V_{CC} = 2.5 V to 5.5 V, over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITION	MIN	TYP	MAX	UNIT
DRV5015A1-Q1, DRV5015A2-Q1, DRV5015A3-Q1						
f_{BW}	Sensing bandwidth		20	30		kHz
DRV5015A1-Q1						
B_{OP}	Magnetic threshold operate point	T_A = –40°C to +125°C	–0.2	0.7	2.0	mT
		T_A = –40°C to +150°C	–0.5	0.7	2.9	mT
B_{RP}	Magnetic threshold release point	T_A = –40°C to +125°C	–2.0	–0.7	0.2	mT
		T_A = –40°C to +150°C	–2.9	–0.7	0.5	mT
B_{HYS}	Magnetic hysteresis: $\lvert B_{OP} - B_{RP} \rvert$	T_A = –40°C to +125°C	0.35	1.4		mT
B_{HYS}	Magnetic hysteresis: $\lvert B_{OP} - B_{RP} \rvert$	T_A = –40°C to +150°C	0.3	1.4		mT
DRV5015A2-Q1, DRV5015A3-Q1						
B_{OP}	Magnetic threshold operate point	T_A = –40°C to +125°C	0.5	1.8	3.7	mT
		T_A = –40°C to +150°C	0.2	1.8	4.5	mT
B_{RP}	Magnetic threshold release point	T_A = –40°C to +125°C	–3.7	–1.8	–0.5	mT
		T_A = –40°C to +150°C	–4.5	–1.8	–0.2	mT
B_{HYS}	Magnetic hysteresis: $\lvert B_{OP} - B_{RP} \rvert$	T_A = –40°C to +125°C	2.3	3.6		mT
B_{HYS}	Magnetic hysteresis: $\lvert B_{OP} - B_{RP} \rvert$	T_A = –40°C to +150°C	1.75	3.6		mT

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6.7 Typical Characteristics

at T_A = 25°C typical (unless otherwise noted)

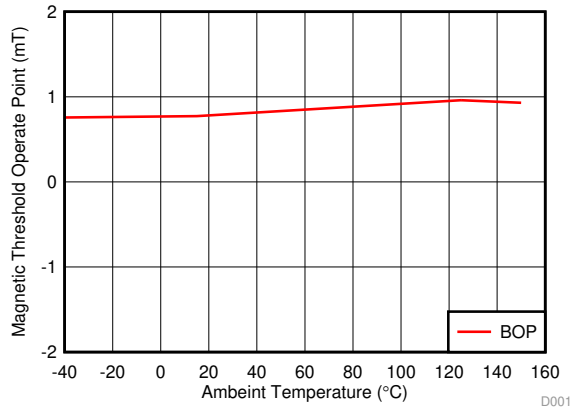

図 1. B_{OP} Threshold vs Temperature (DRV5015A1-Q1)

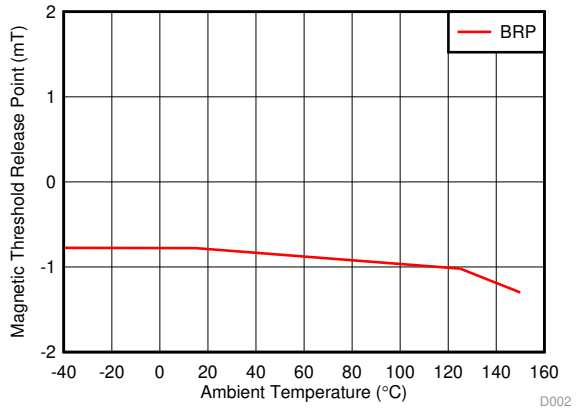

図 2. B_{RP} Threshold vs Temperature (DRV5015A1-Q1)

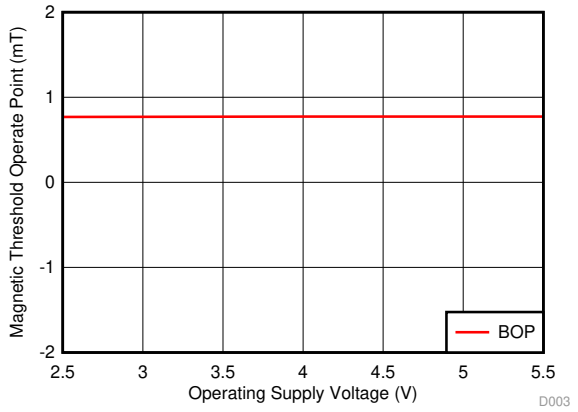

図 3. B_{OP} Threshold vs Supply Voltage (DRV5015A1-Q1)

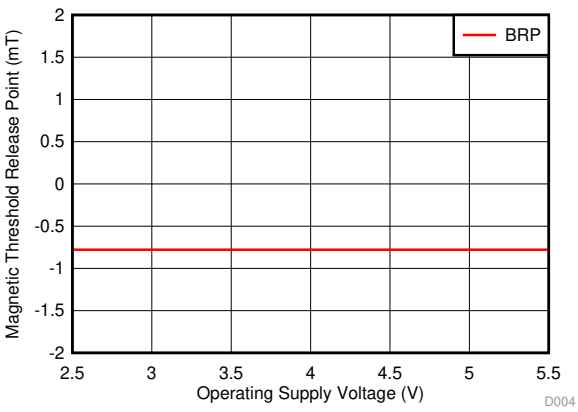

図 4. B_{RP} Threshold vs Supply Voltage (DRV5015A1-Q1)

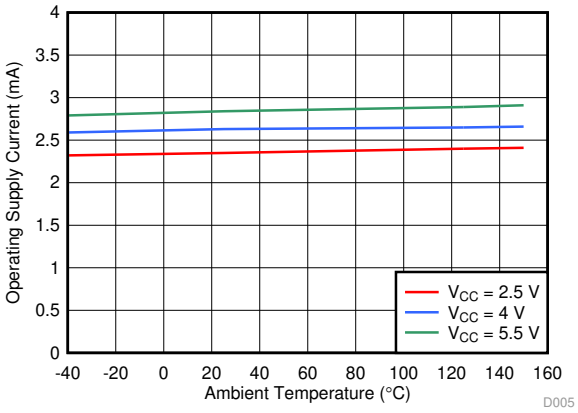

図 5. I_{CC} vs Temperature (DRV5015A1-Q1)

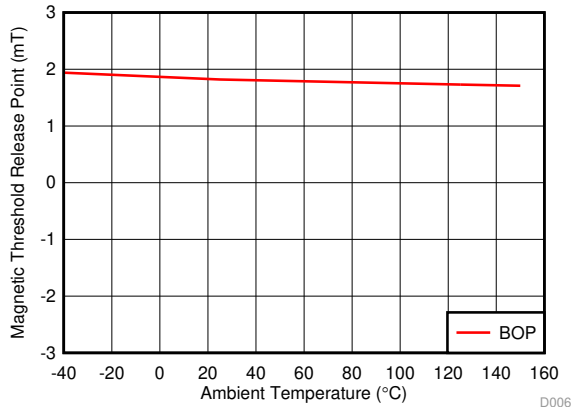

図 6. B_{OP} Threshold vs Temperature (DRV5015A2-Q1, DRV5015A3-Q1)

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Typical Characteristics (continued)

at T_A = 25°C typical (unless otherwise noted)

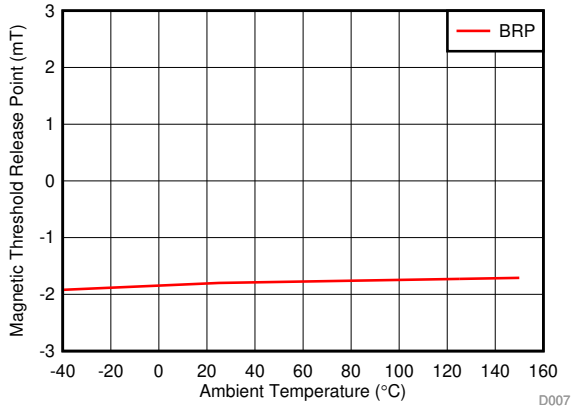

図 7. B_{RP} Threshold vs Temperature (DRV5015A2-Q1, DRV5015A3-Q1)

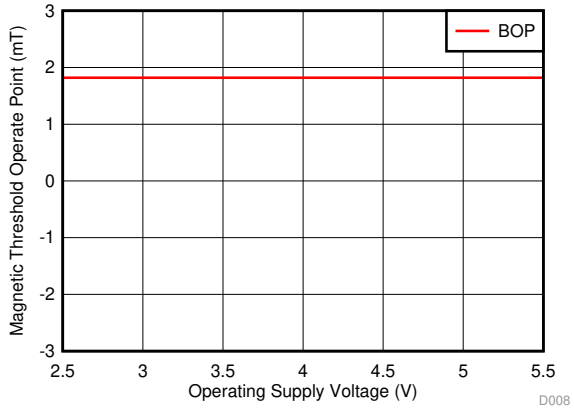

図 8. B_{OP} Threshold vs Supply Voltage (DRV5015A2-Q1, DRV5015A3-Q1)

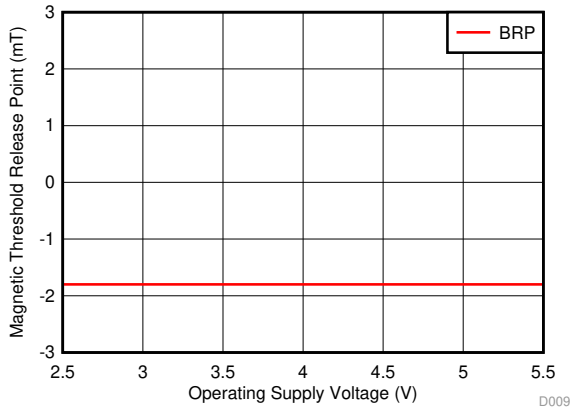

図 9. B_{RP} Threshold vs Supply Voltage (DRV5015A2-Q1, DRV5015A3-Q1)

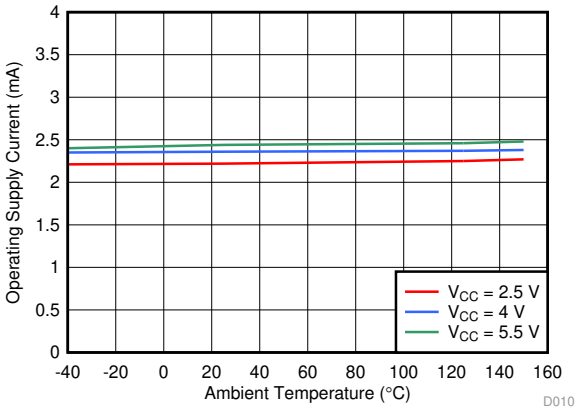

図 10. I_{CC} vs Temperature (DRV5015A2-Q1, DRV5015A3-Q1)

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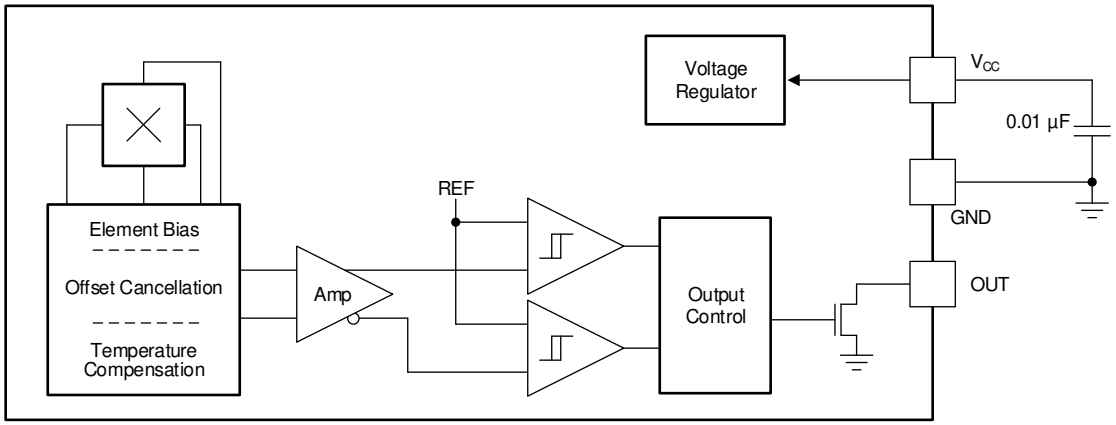
7 Detailed Description

7.1 Overview

The DRV5015-Q1 is a magnetic sensor with a digital output that latches the most recent pole measured. During power-up, in the absence of an external magnetic field, the DRV5015A1-Q1 and DRV5015A2-Q1 default to a low output state and the DRV5015A3-Q1 defaults to a high output state. Applying a south magnetic pole near the top of the package causes the DRV5015A1-Q1 and DRV5015A2-Q1 output to drive low, whereas a north magnetic pole causes this output to drive high. Applying a south magnetic pole near the top of the package causes the DRV5015A3-Q1 output to drive high, whereas a north magnetic pole causes this output to drive low. The absence of a magnetic field causes the output to continue to drive the current state, whether low or high.

The device integrates a Hall effect element, analog signal conditioning, offset cancellation circuits, amplifiers, and comparators. These features provide stable performance across a wide temperature range and resistance to mechanical stress.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Magnetic Flux Direction

As shown in 図 11, the DRV5015-Q1 is sensitive to the magnetic field component that is perpendicular to the top of the package.

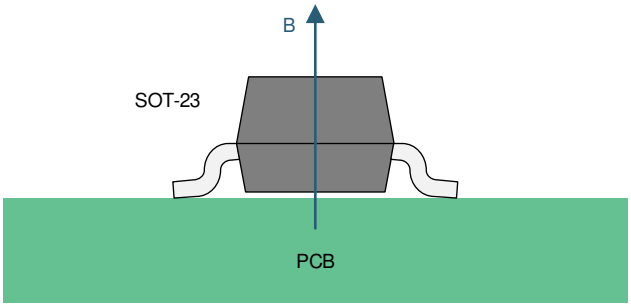


図 11. Direction of Sensitivity

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Feature Description (continued)

Magnetic flux that travels from the bottom to the top of the package is considered positive in this document. This condition exists when a south magnetic pole is near the top of the package. Magnetic flux that travels from the top to the bottom of the package is considered negative. 図 12 shows the flux direction polarity.

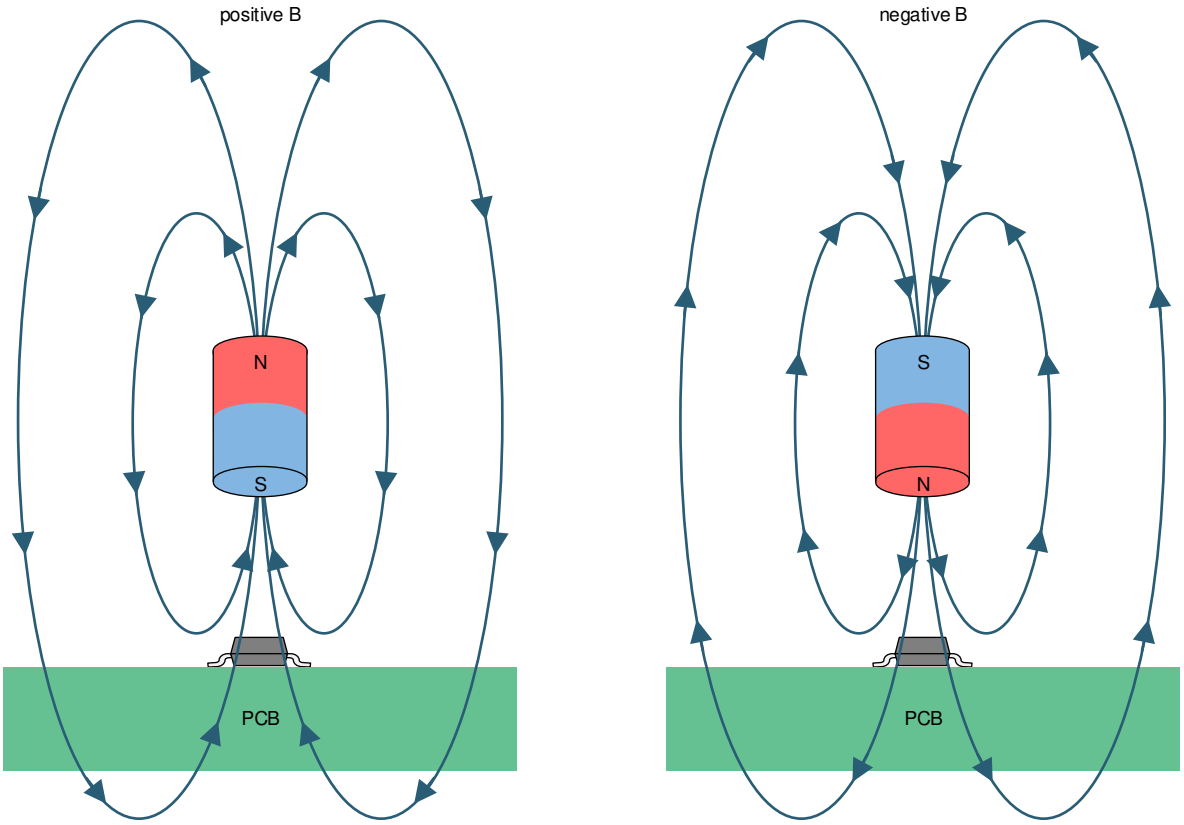

図 12. Flux Direction Polarity

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Feature Description (continued)

7.3.2 Magnetic Response

図 13 shows the device output response to stimulus and hysteresis.

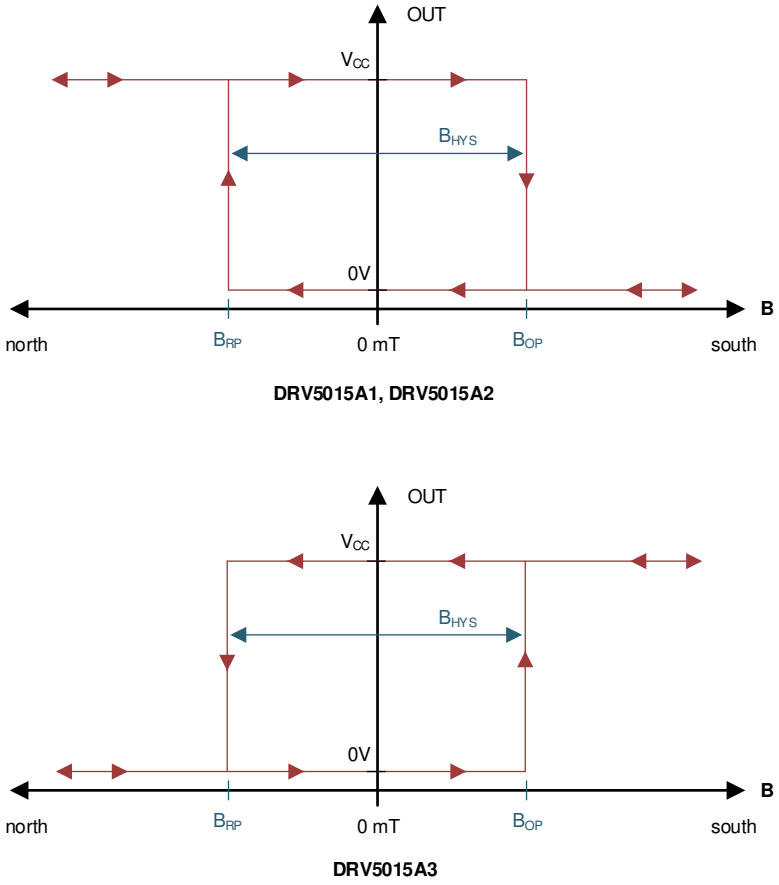

図 13. Device Output Response to Stimulus

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Feature Description (continued)

7.3.3 Output Driver

図 14 shows the DRV5015-Q1 open-drain output structure. An open-drain output offers flexibility by enabling system designers to interface to wide-range GPIO termination voltages. C1 represents the input capacitance of the GPIO. R1 represents the pullup resistor connected to the termination voltage, $V_{PULL-UP}$. The maximum allowable value of V_{PULL_UP} is 5.5 V. The value of R1 must be selected after proper considerations among the system speed and the power dissipation through the pullup resistor.

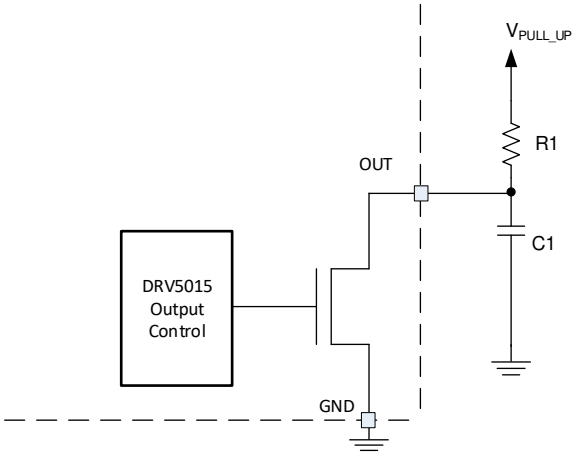

図 14. Open-Drain Output (Simplified)

7.3.4 Power-On Time

図 15 shows that after the V_{CC} voltage is applied, the DRV5015-Q1 measures the magnetic field and sets the output within the t_{ON} time.

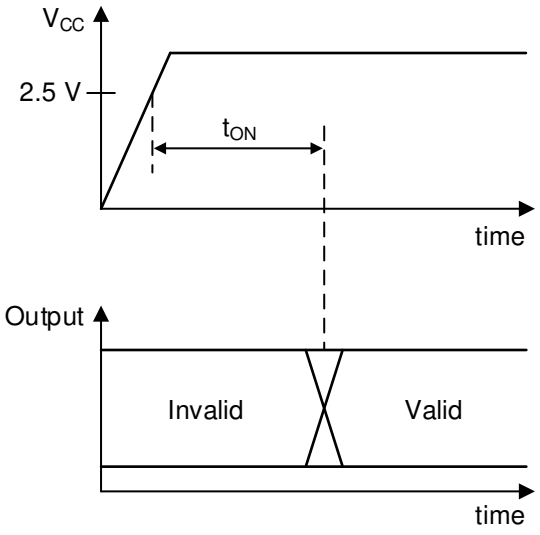

図 15. t_{ON} Definition

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Feature Description (continued)

7.3.5 Hall Element Location

The sensing element inside the device is in the center of both packages when viewed from the top. 図 16 shows the tolerances and side-view dimensions.

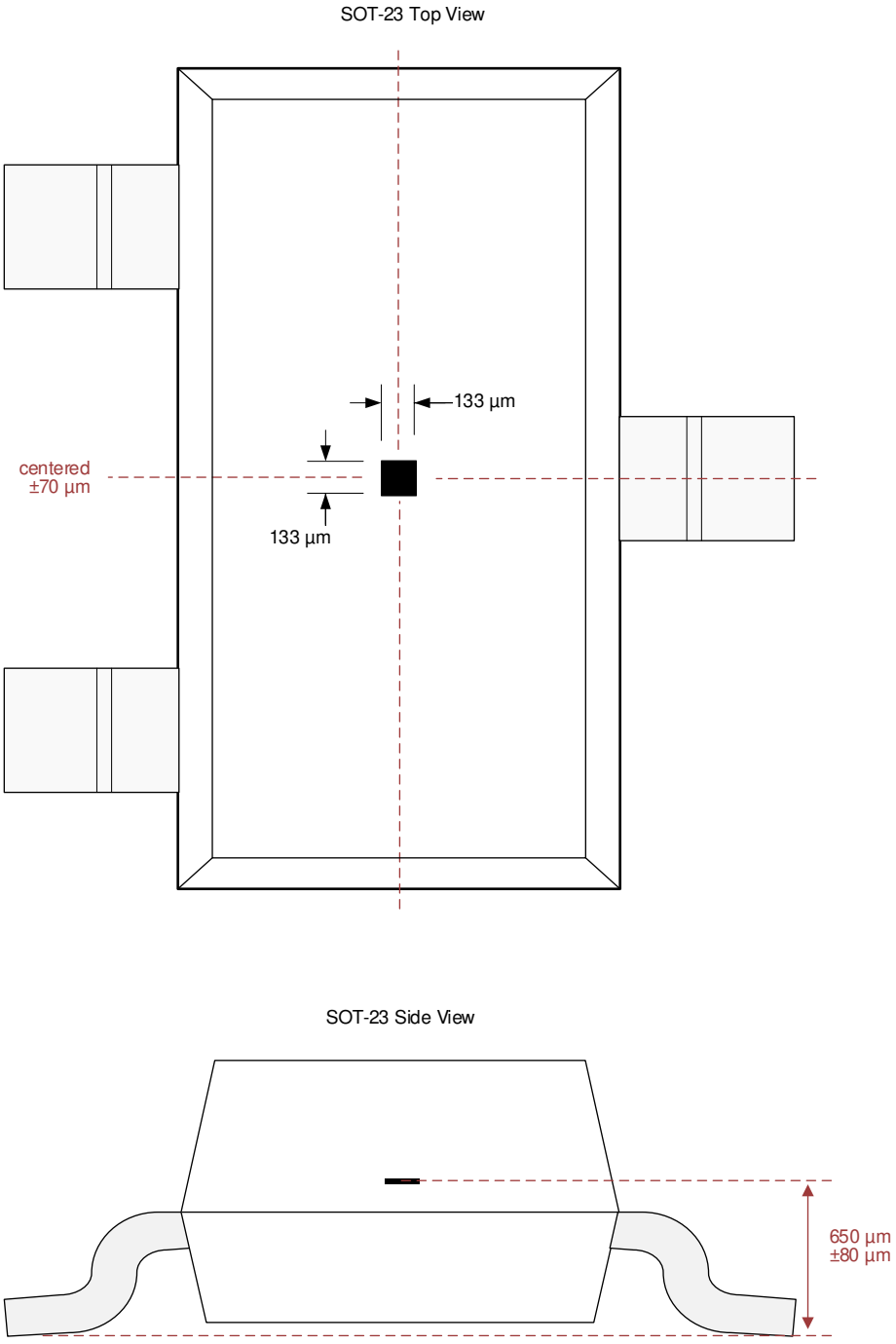

図 16. Hall Element Location

Feature Description (continued)

7.3.6 Propagation Delay

The DRV5015-Q1 samples the Hall element at a nominal sampling interval of every 16.67 µs to detect the presence of a magnetic north or south pole. At each sampling point, the device takes the average of the current sampled value and immediately preceding sampled value of the magnetic field. If this average value crosses the B_{OP} or B_{RP} threshold, the device output changes to the corresponding state as defined by the *Overview* section.

図 17 shows the DRV5015A1-Q1 propagation delay analysis in the proximity of a magnetic south pole. The Hall element of the DRV5015-Q1 experiences an increasing magnetic field as a magnetic south pole approaches near the device. At time t_2, the average magnetic field is (B_2 + B_1) / 2, which is below the B_{OP} threshold of the device. At time t_3, the actual magnetic field has crossed the B_{OP} threshold. However, the average (B_3 + B_2) / 2 is still less than the B_{OP} threshold. As such, the device waits for next sample time, t_4, to start the output transition through the analog signal chain. The propagation delay, t_d, is measured as the delay from the time the magnetic field crosses the B_{OP} threshold to the time output transitions.

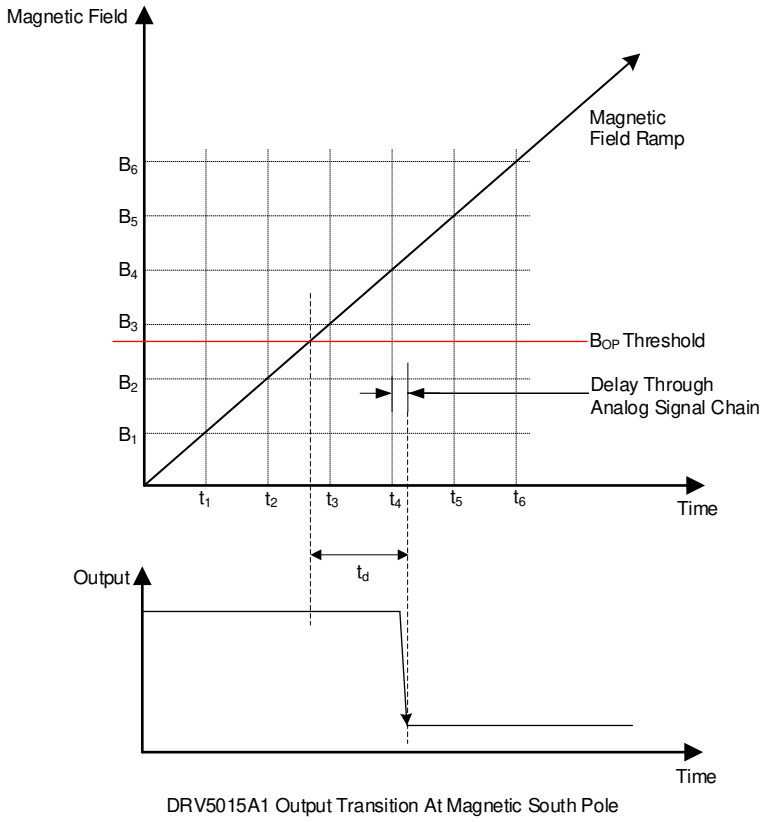

図 17. Propagation Delay

7.4 Device Functional Modes

The DRV5015-Q1 has one mode of operation that applies when the are met.

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8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The DRV5015-Q1 is ideal for use in rotary applications for brushless DC (BLDC) motor sensors or incremental rotary encoding.

For reliable functionality, the magnet must apply a flux density at the sensor greater than the corresponding maximum B_{OP} or B_{RP} numbers specified in the table. Add additional margin to account for mechanical tolerance, temperature effects, and magnet variation. Magnets generally produce weaker fields as temperature increases.

8.2 Typical Applications

8.2.1 BLDC Motor Sensors Application

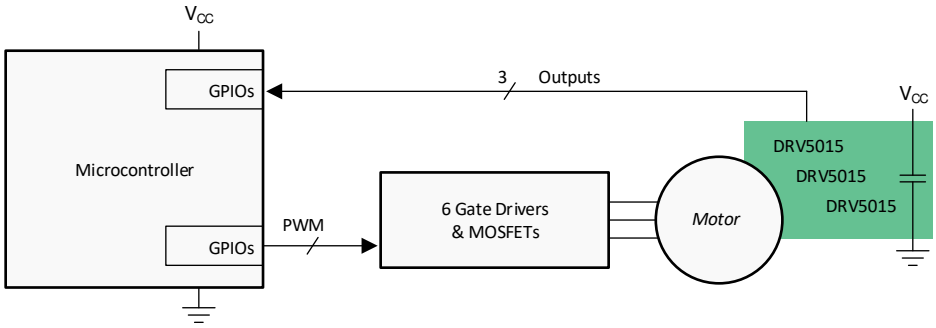

図 18. BLDC Motor System

8.2.1.1 Design Requirements

Use the parameters listed in 表 1 for this design.

表 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Number of motor phases	3
Motor RPM	15 kRPM
Number of magnet poles on the rotor	12
Magnetic material	Bonded neodymium
Maximum temperature inside the motor	150°C
Magnetic flux density peaks at the Hall sensors at maximum temperature	±11 mT
Hall sensor V_{CC}	5 V ± 10%

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8.2.1.2 Detailed Design Procedure

Three-phase brushless DC motors often use three Hall effect latch devices to measure the electrical angle of the rotor and tell the controller how to drive the three wires. These wires connect to electromagnet windings, which generate magnetic fields that apply forces to the permanent magnets on the rotor.

Space the three Hall sensors across the printed-circuit board (PCB) so that these sensors are 120 electrical degrees apart. This configuration creates six 3-bit states with equal time duration for each electrical cycle, which consists of one north and one south magnetic pole. From the center of the motor axis, the number of degrees to space each sensor equals *2 / [number of poles] × 120°*. In this design example, the first sensor is placed at 0°, the second sensor is placed 20° rotated, and the third sensor is placed 40° rotated. Alternatively, a 3× degree offset can be added or subtracted to any sensor, meaning that the third sensor can alternatively be placed at 40° – (3 × 20°) = –20°.

8.2.1.3 Application Curve

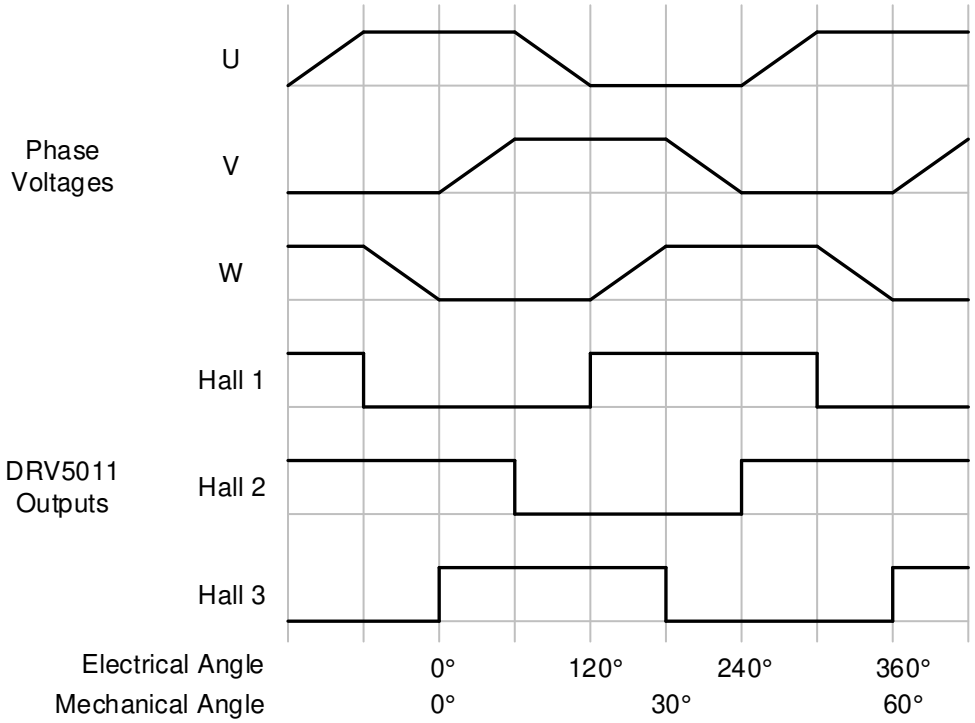

図 19. Phase Voltages and Hall Signals for a 3-Phase BLDC Motor

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8.2.2 Incremental Rotary Encoding Application

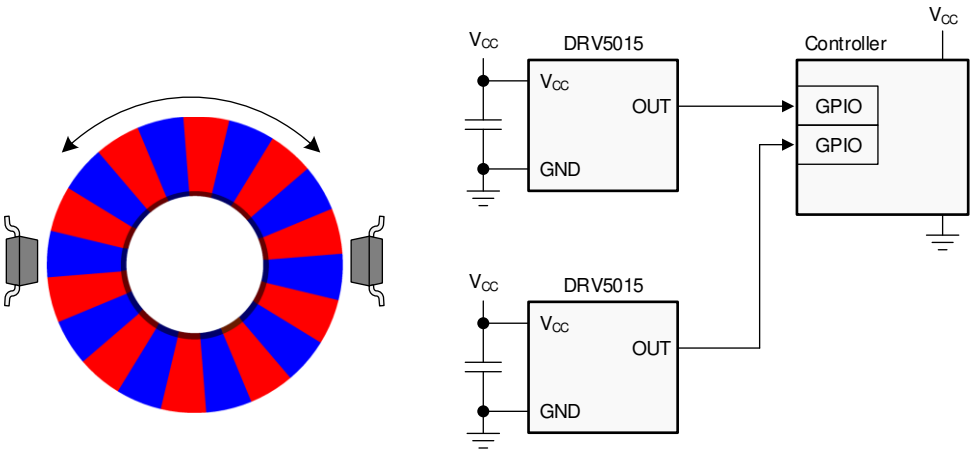

図 20. Incremental Rotary Encoding System

8.2.2.1 Design Requirements

Use the parameters listed in 表 2 for this design.

表 2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
RPM range	45 kRPM
Number of magnet poles	8
Magnetic material	Ferrite
Air gap above the Hall sensors	2.5 mm
Magnetic flux density peaks at the Hall sensors at maximum temperature	±7 mT

8.2.2.2 Detailed Design Procedure

Incremental encoders are used on knobs, wheels, motors, and flow meters to measure relative rotary movement. By attaching a ring magnet to the rotating component and placing a DRV5015-Q1 nearby, the sensor generates voltage pulses as the magnet turns. If directional information is also needed (clockwise versus counterclockwise), a second DRV5015-Q1 can be added with a phase offset, and then the order of transitions between the two signals describes the direction.

Creating this phase offset requires spacing the two sensors apart on the PCB, and an ideal 90° quadrature offset is attained when the sensors are separated by half the length of each magnet pole, plus any integer number of pole lengths. 図 20 shows this configuration because the sensors are 1.5 pole lengths apart. One of the sensors changes its output every *360° / 8 poles / 2 sensors* = 22.5° of rotation. For reference, the *TIDA-00480 TI Design Considerations Automotive Hall Sensor Rotary Encoder* uses a 66-pole magnet with changes every 2.7°.

The maximum rotational speed that can be measured is limited by the sensor bandwidth. Generally, the bandwidth must be faster than two times the number of poles per second. In this design example, the maximum speed is 45000 RPM, which involves 6000 poles per second. The DRV5015-Q1 sensing bandwidth is typically 30 kHz, which is five times the pole frequency. In systems where the sensor sampling rate is close to two times the number of poles per second, most of the samples measure a magnetic field that is significantly lower than the peak value, because the peaks only occur when the sensor and pole are perfectly aligned. In this case, add margin by applying a stronger magnetic field that has peaks significantly higher than the maximum B_{OP}.

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8.2.2.3 Application Curve

Two signals in quadrature provide movement and direction information. 図 21 shows how each 2-bit state has unique adjacent 2-bit states for clockwise and counterclockwise.

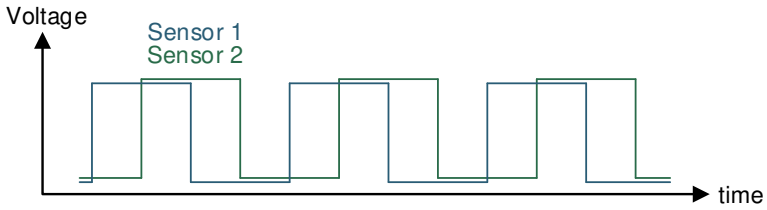

図 21. Quadrature Output (2-Bit)

8.3 What to Do and What Not to Do

The Hall element is sensitive to magnetic fields that are perpendicular to the top of the package; therefore, the correct magnet orientation must be used for the sensor to detect the field. 図 22 shows correct and incorrect orientations when using a ring magnet.

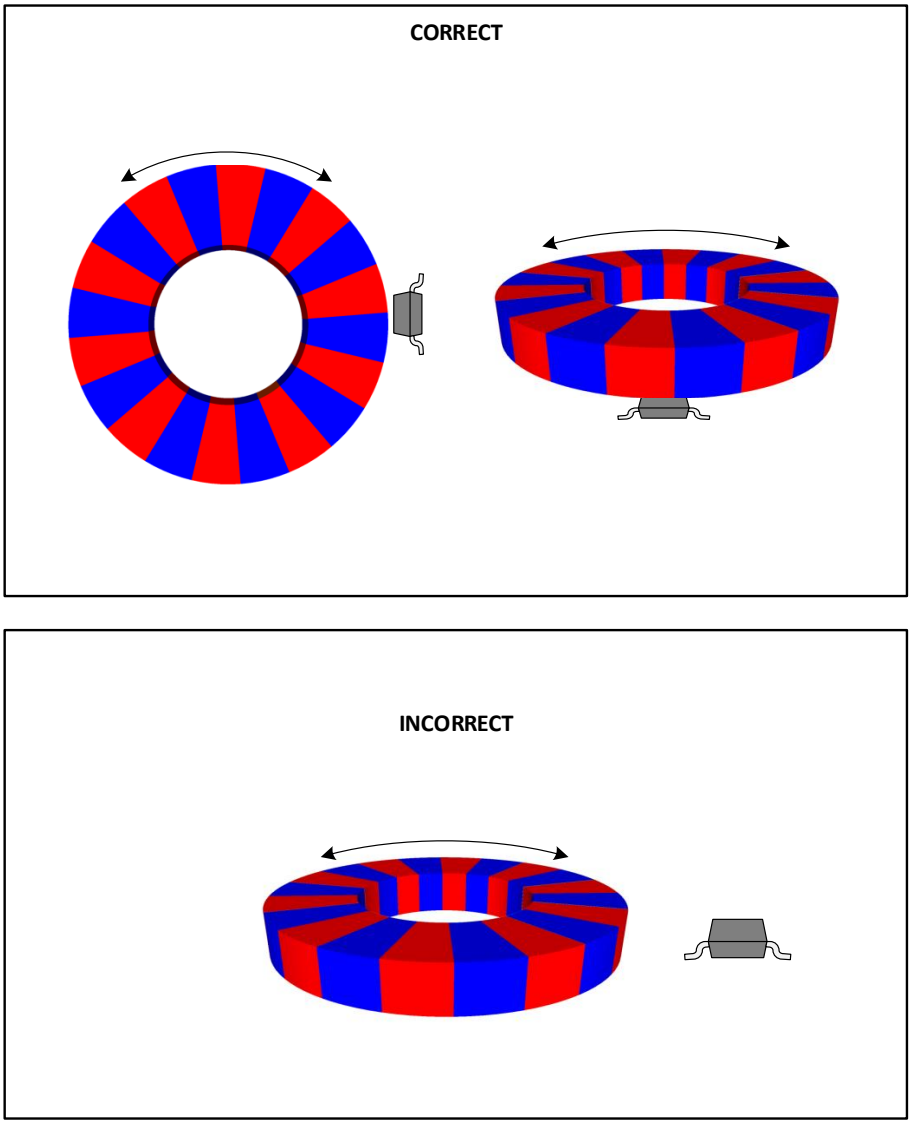

図 22. Correct and Incorrect Magnet Orientations

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9 Power Supply Recommendations

The DRV5015-Q1 is powered from 2.5-V to 5.5-V DC power supplies. A decoupling capacitor close to the device must be used to provide local energy with minimal inductance. TI recommends using a ceramic capacitor with a value of at least 0.01 µF.

10 Layout

10.1 Layout Guidelines

Magnetic fields pass through most nonferromagnetic materials with no significant disturbance. Embedding Hall effect sensors within plastic or aluminum enclosures and sensing magnets on the outside is common practice. Magnetic fields also easily pass through most PCBs, which makes placing the magnet on the opposite side of the PCB possible.

10.2 Layout Example

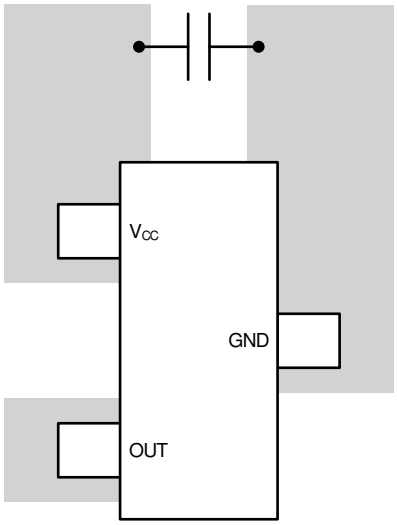

図 23. Example Layout

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11 デバイスおよびドキュメントのサポート

11.1 ドキュメントのサポート

11.1.1 関連資料

関連資料については、以下を参照してください。

- *『TIDA-00480 車載用ホール・センサ・ロータリー・エンコーダのTI Designの考慮事項』*
- *『HALL-ADAPTER-EVMユーザー・ガイド』*

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11.3 コミュニティ・リソース

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Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DRV5015A1EDBZRQ1	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 150	151Z
DRV5015A1EDBZRQ1.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 150	151Z
DRV5015A2EDBZRQ1	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 150	152Z
DRV5015A2EDBZRQ1.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 150	152Z
DRV5015A3EDBZRQ1	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 150	153Z
DRV5015A3EDBZRQ1.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 150	153Z

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF DRV5015-Q1 :

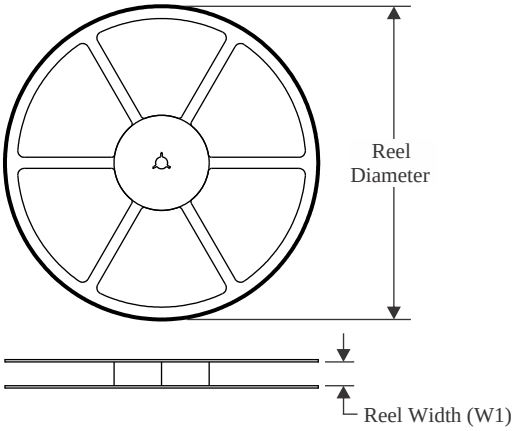
- Catalog : DRV5015

NOTE: Qualified Version Definitions:

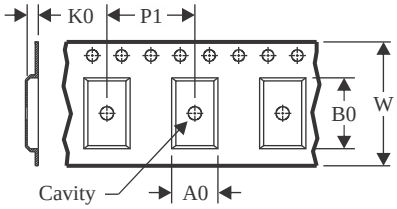
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS

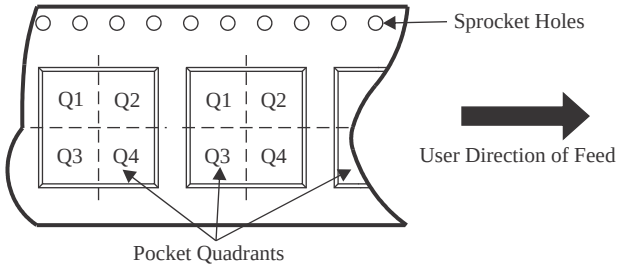


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

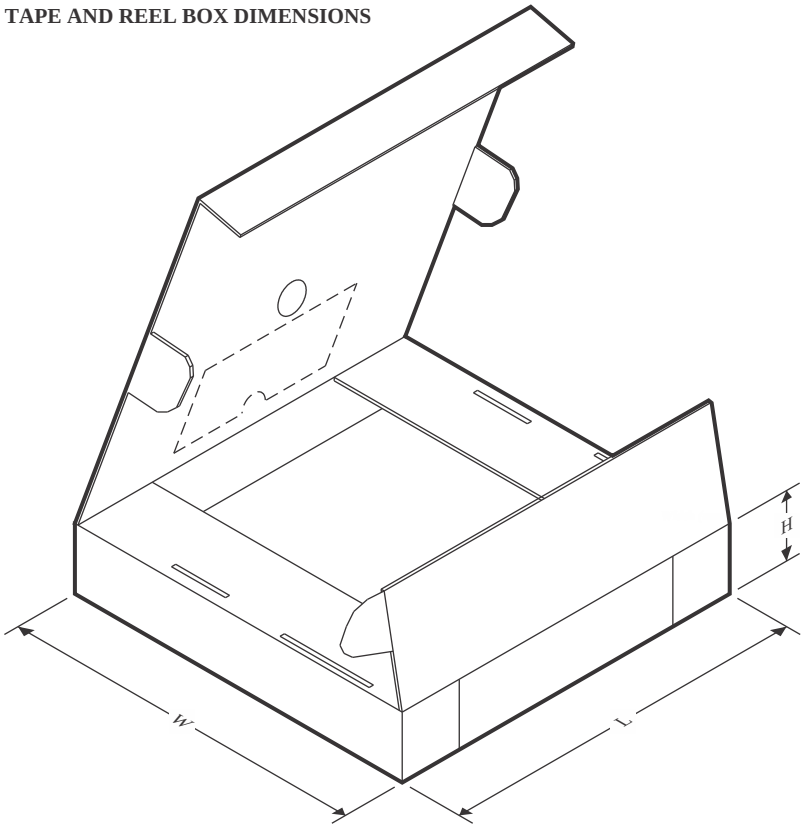
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DRV5015A1EDBZRQ1	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5015A1EDBZRQ1	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
DRV5015A2EDBZRQ1	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
DRV5015A3EDBZRQ1	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

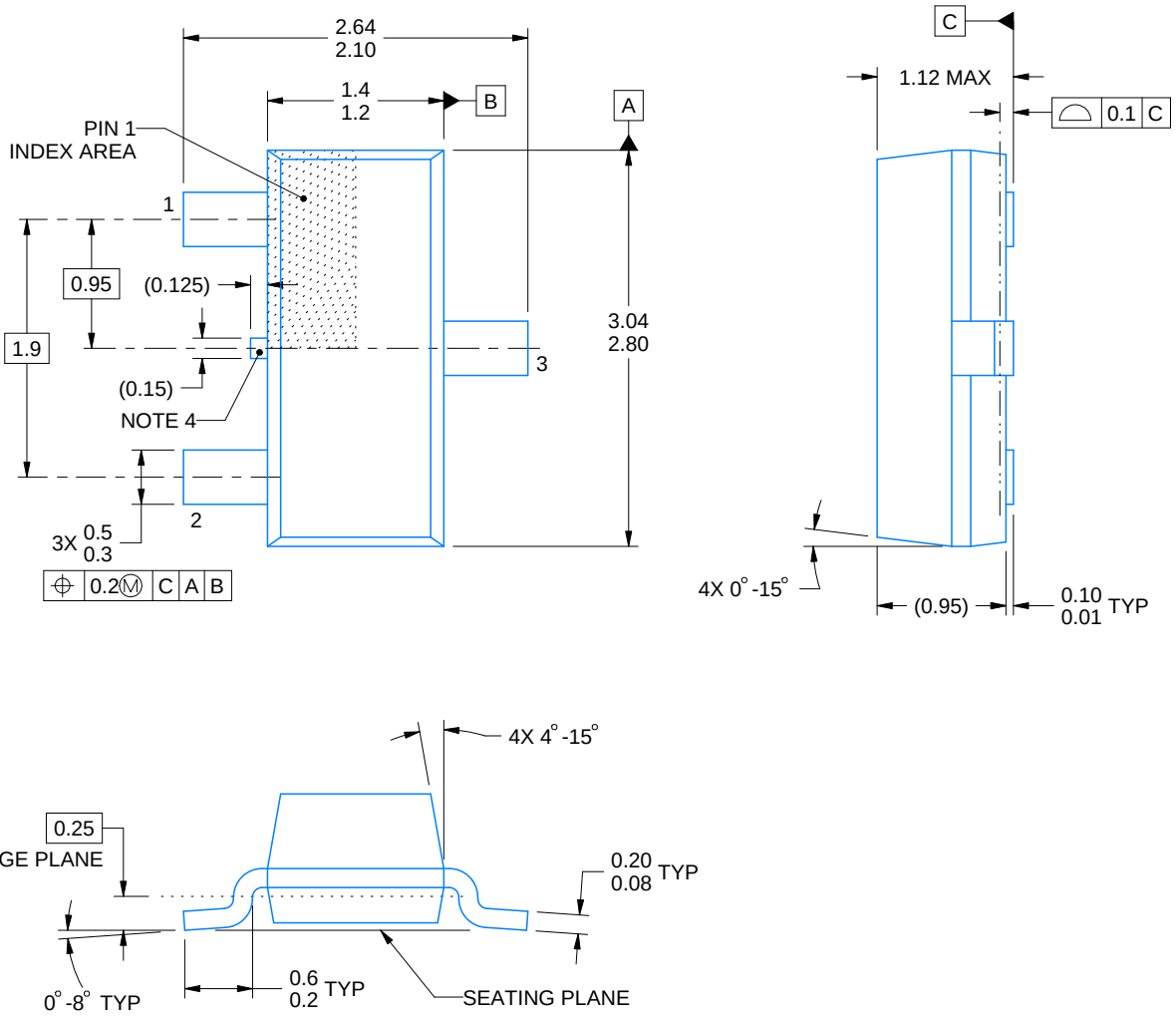
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DRV5015A1EDBZRQ1	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5015A1EDBZRQ1	SOT-23	DBZ	3	3000	180.0	180.0	18.0
DRV5015A2EDBZRQ1	SOT-23	DBZ	3	3000	180.0	180.0	18.0
DRV5015A3EDBZRQ1	SOT-23	DBZ	3	3000	180.0	180.0	18.0

PACKAGE OUTLINE

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



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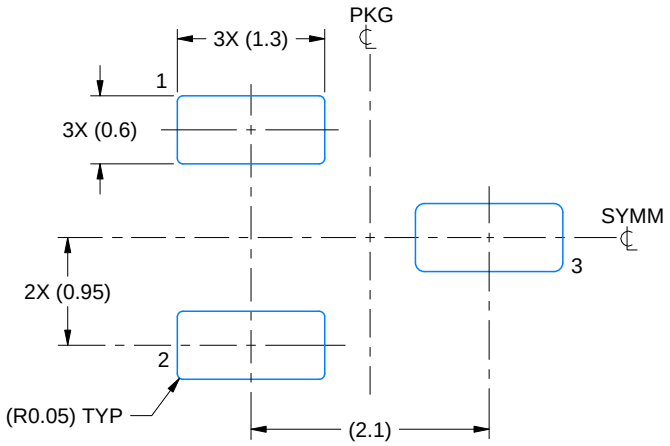
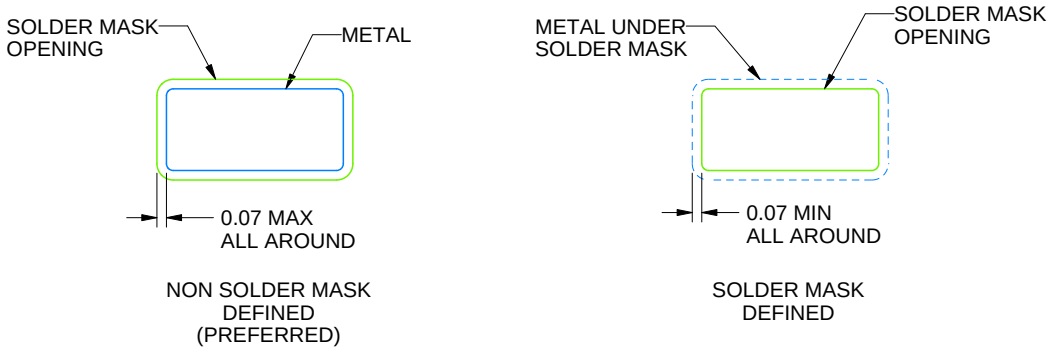
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.
4. Support pin may differ or may not be present.
5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



LAND PATTERN EXAMPLE
SCALE:15X



SOLDER MASK DETAILS

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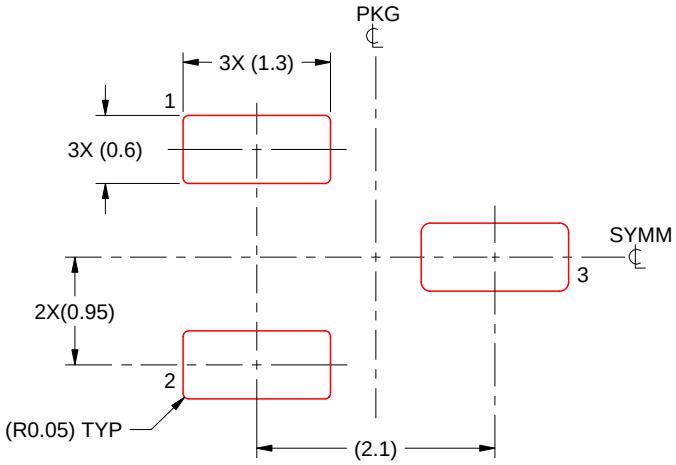
NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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